

Features

- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

PNP Plastic Encapsulate Transistor

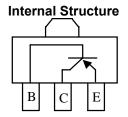
Maximum Ratings

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 250 °C/W Junction to Ambient

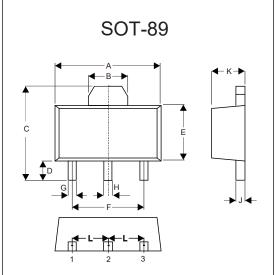
Parameter	Symbol	Rating	Unit
Collector-Base Voltage	V _{CBO}	-100	V
Collector-Emitter Voltage	V _{CEO}	-80	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	Ic	-1.0	Α
		500	mW ^(Note2)
Collector Power Dissipation	P _C	950	mW ^(Note3)
		1350	mW ^(Note4)

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

- 2.Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, t in-plated and standard footprint.
- 3.Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 $\,\mathrm{cm^2}$.
- 4.Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 $\mbox{cm}^2.$

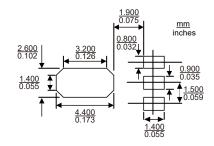


Marking: BCX53=AH, BCX53-10=AK BCX53-16=AL



DIMENSIONS							
DIM	INCHES		MM		NOTE		
	MIN	MAX	MIN	MAX	NOTE		
Α	0.169	0.185	4.30	4.70			
В	0.061		1.55		TYP.		
С	0.154	0.171	3.91	4.35			
D	0.031	0.047	0.80	1.20			
Е	0.089	0.104	2.25	2.65			
F	0.118		3.00		TYP.		
G	0.013	0.020	0.33	0.52			
Н	0.015	0.021	0.38	0.53			
J	0.014	0.017	0.35	0.44			
K	0.055	0.063	1.40	1.60			
L	0.059		1.50		TYP.		

Suggested Solder Pad Layout





Electrical Characteristics @ 25°C Unless Otherwise Specified

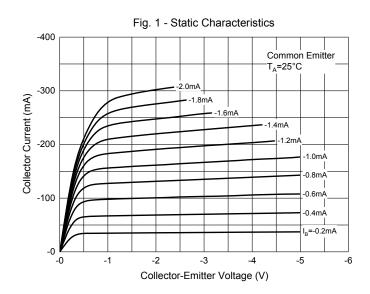
Parameter		Symbol	Min	Тур	Max	Units	Conditions
Collector-Base Breakdown Voltage		V _{(BR)CBO}	-100			V	I _C =-100μA, I _E =0
Collector-Emitter Breakdown Voltage ^(Note5)		V _{(BR)CEO}	-80			V	I _C =-10mA, I _B =0
Emitter-Base Breakdown Voltage		$V_{(BR)EBO}$	-5			V	I _E =-100μA, I _C =0
Collector Cutoff Current		I _{CBO}			-0.1	μA	V _{CB} =-30V, I _E =0
Emitter-Base Cutoff Current		I _{EBO}			-0.1	μA	V_{EB} =-5V, I_C =0
DC Current Gain ^{(Note5}		h _{FE1}	63				V _{CE} =-2V, I _C =-5mA
DC Current Gain ^(Note5)	BCX53	h _{FE2}	63		250		V _{CE} =-2V, I _C =-150mA
	BCX53-10		63		160		
	BCX53-16		100		250		
DC Current Gain ^(Note5)		h _{FE3}	40				V _{CE} =-2V, I _C =-500mA
Collector-Emitter Saturation Voltage ^(Note5)		V _{CE(sat)}			-0.5	V	I _C =-500mA, I _B =-50mA
Base-Emitter Saturation Voltage(Note5)		V _{BE(sat)}			-1.0	V	I _C =-500mA, V _{CE} =-2.0V
Transition Frequency		f _T		50		MHz	V _{CE} =-5V, I _C =-10mA, f=100MHz

Note:

5.Pulse Test



Curve Characteristics



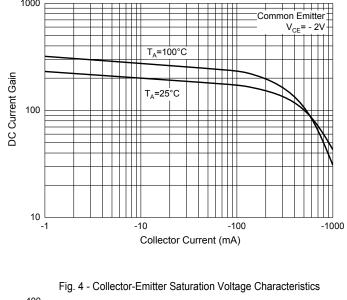
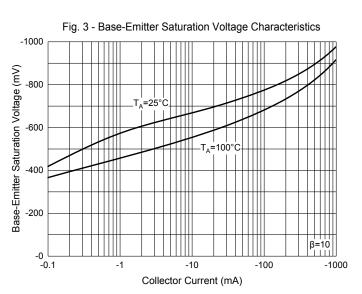
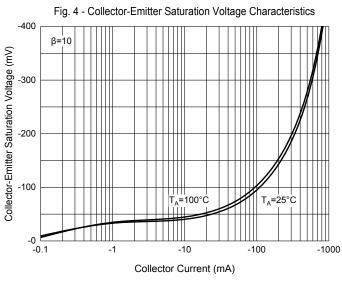
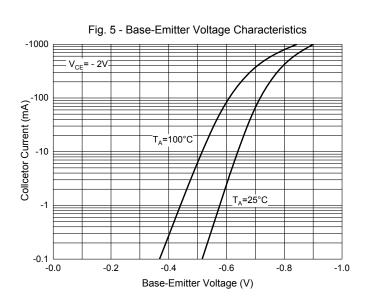


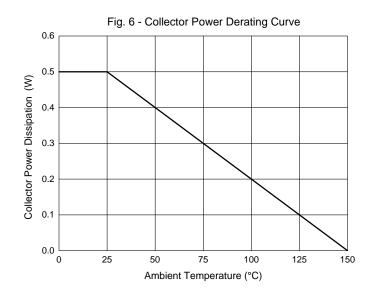
Fig. 2 - DC Current Gain Characteristics

1000











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